

Symmetries and selection rules in the measurement of the phonon spectrum of graphene and related materials

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When the phonon spectrum of a material is measured in a scattering experiment, selection rules preclude the observation of phonons that are odd under reflection by the scattering plane. Understanding these rules is crucial to correctly interpret experiments and to detect broken symmetries. Taking graphene as a case study, in this work we derive the complete set of selection rules for the honeycomb lattice, showing that some of them have been missed or misinterpreted in the literature. Focusing on the technique of high-resolution electron energy loss spectroscopy (HREELS), we calculate the scattering intensity for a simple force constant model to illustrate these rules. In addition, we present HREELS measurements of the phonon dispersion for graphene on Ru(0001) and find excellent agreement with the theory. We also illustrate the effect of different symmetry breaking scenarios in the selection rules and discuss previous experiments in light of our results.

I. INTRODUCTION

The investigation of surface phonons is an invaluable tool to study materials^{1,2}, as it provides a wealth of information on their structural³, electronic⁴, magnetic⁵ or thermal properties⁶, to name a few. Among many experimental probes, surface scattering experiments are particularly well suited to measure phonon spectra. As in any scattering setup, however, the mapping of the full phonon dispersion with these methods is sometimes limited by selection rules^{1,7}, which preclude the observation of certain phonon branches. The understanding of these rules is therefore crucial in the design and interpretation of these experiments.

The origin of selection rules is the presence of symmetries that enforce conservation laws. In surface scattering experiments, a selection rule applies when the scattering plane, defined by the momenta of the incident and scattered particles, coincides with a mirror plane of the surface. The selection rule states that phonons that are odd under this mirror reflection cannot be observed^{7–10}, and can be easily understood as the conservation of parity under reflections: since incoming and scattered wavefunctions of the probe have even parity, the excitation of an odd parity phonon is forbidden, and the contribution to the cross section from this process is zero.

In experiments, the simplest geometry to measure phonon dispersions is planar scattering, with the scattering plane perpendicular to the surface. Since one is usually interested in the dispersion along high symmetry directions, the scattering plane is often a mirror plane and selection rules apply. Knowledge of these rules can thus be of great help to interpret the data, for example to assign symmetry labels to phonon branches or to detect broken symmetries. Moreover, this understanding can be used to devise more complicated non-planar scat-

tering geometries^{9–13} that are not affected by selection rules and allow one to observe the odd modes¹⁴.

To measure phonon dispersions, one of the most powerful experimental probes is high-resolution electron energy loss spectroscopy (HREELS). Among other advantages, this technique offers excellent energy and momentum resolution and allows one to map the full phonon spectrum. HREELS has been applied to many systems with great success, and is very useful in particular to measure the spectrum of epitaxial monolayers grown on a substrate, where inelastic neutron or X-ray scattering cannot be used. A well known example is the case of graphene monolayers, where the effect of different substrates on the phonon spectrum has been widely studied^{15–28}.

The case of HREELS studies of epitaxial graphene is of particular interest because, despite the many experiments reported, their interpretation in terms of selection rules has often been misleading. While most studies acknowledge the existence of a selection rule which forbids the observation of the shear horizontal mode, SH, (or transverse acoustic, TA) along the ΓM direction, other selection rules are sometimes misquoted and some have been completely missed. The purpose of this work is to provide a detailed study of the selection rules for surfaces with C_{6v} symmetry, taking the case of graphene as an example. Our main result is the full set of selection rules, summarized in Fig. 1: the modes TA and TO along the ΓM direction and the modes TA, ZO and LO along ΓK are all odd and thus should not be observed. Our results are worked out for HREELS for concreteness, but are equally applicable to any other planar scattering experiment.

In the rest of this work, we first discuss how selection rules appear in the computation of the HREELS scattering rate. We illustrate our results for this with a simplified phonon model, and we compare them with our experimental HREELS data for graphene on Ru(0001).

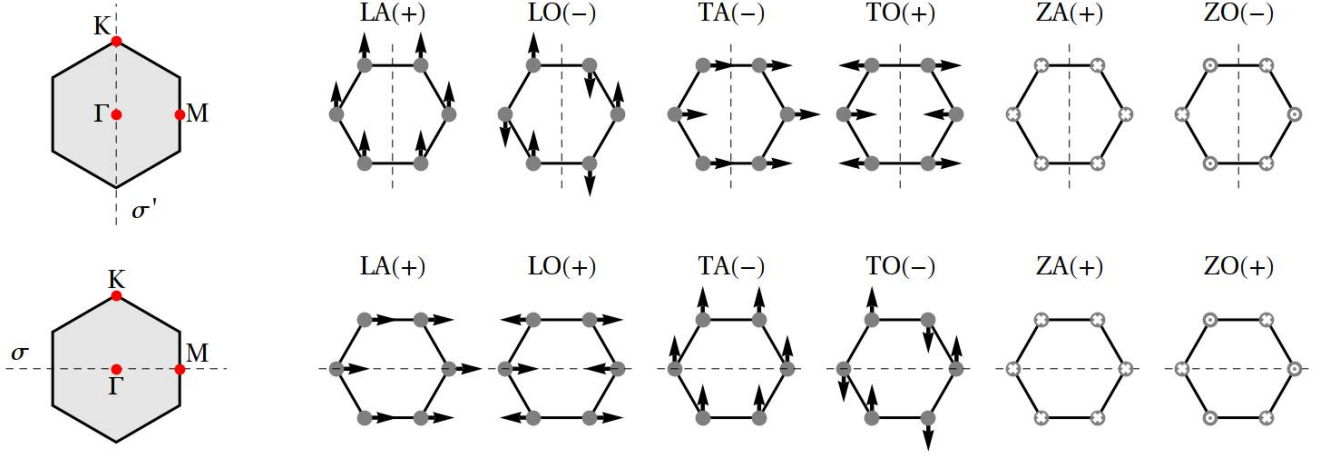


FIG. 1. Honeycomb lattice phonon eigenvectors at the Γ point, with their polarization defined with respect to the ΓK (top) and ΓM (bottom) directions. Out of plane displacement is indicated by crosses (positive) and circles (negative). The mirror planes σ' (that leaves ΓK invariant) and σ (that leaves ΓM invariant) are represented as dashed lines. The parity of each phonon under the corresponding reflection is indicated in parenthesis. Phonons with odd (-) parity are not observed in HREELS.

Finally, we will discuss how symmetry breaking can render selection rules inactive, and interpret previous experiments in light of our results.

II. SELECTION RULES IN THE HREELS INTENSITY

The origin of the selection rule explained in the introduction can be seen more explicitly by considering the computation of the HREELS cross section^{7,29} due to phonon excitations. The relevant kinematic regime for this process is known as impact scattering, where high-energy electrons interact with the short-range part of the atomic potential. The incoming electron with energy E_I and momentum \mathbf{k}_I is scattered off a surface and is recovered with energy E_S and momentum \mathbf{k}_S . The excitation of a phonon of frequency ω and momentum \mathbf{q} is detected in the loss spectrum as a resonance peak at $E_S = E_I \pm \omega$ and $\mathbf{k}_S = \mathbf{k}_I \pm \mathbf{q}$.

Because of the geometry of this problem it will be convenient to separate vectors into in-plane and out of plane components, $\mathbf{q} = (\vec{q}_{\parallel}, q_z)$, reserving the arrow notation \vec{q} for two-dimensional vectors in the plane. For a given phonon of momentum \vec{q}_{\parallel} in the Brillouin Zone (BZ) and eigenvector $\mathbf{u}^{\alpha}(\vec{q}_{\parallel})$, where α labels the different atoms in the unit cell, the scattering amplitude in the impact scattering regime is proportional to the matrix element²⁹

$$M = \sum_{\alpha} e^{i\vec{q}_{\parallel} \cdot \vec{x}_{\alpha}} \mathbf{q} \cdot \mathbf{u}^{\alpha} = \sum_{\alpha} e^{i\vec{q}_{\parallel} \cdot \vec{x}_{\alpha}} \left[\vec{q}_{\parallel} \cdot \vec{u}_{\parallel}^{\alpha} + q_z u_z^{\alpha} \right], \quad (1)$$

where \vec{x}_{α} is the position of atom α in the unit cell. The scattering rate is proportional to $|M|^2$. This matrix element accounts for the dominant changes in intensity as

the BZ is sampled for a fixed E_I . The full theory for the scattering cross section can be found in Refs. 7 and 29, but knowledge of Eq. 1 will suffice for our purposes.

The selection rules can now be explained in terms of Eq. 1. When the scattering plane is aligned with a mirror plane of the surface, \mathbf{q} is invariant under the mirror plane. The phonon eigenvectors at the corresponding q_{\parallel} can thus be chosen with well defined parity under this symmetry. The selection rule occurs because the matrix element must be invariant under the symmetry, and since \mathbf{q} is invariant, when $\mathbf{u}^{\alpha}(q_{\parallel})$ is odd we must have $M = -M$, which implies $M = 0$.

III. APPLICATION TO THE HONEYCOMB LATTICE

The honeycomb lattice has symmetry group C_{6v} , which has two types of mirror planes, σ and σ' represented in Fig. 1. In the BZ, the plane σ' is aligned with the ΓK direction, while the plane σ is aligned with ΓM . The selection rules are simple to state. For any surface with C_{6v} symmetry and in a planar scattering experiment, if q_{\parallel} lies in ΓK odd phonons under σ' are not observed, while if q_{\parallel} lies in ΓM odd phonons under σ are not observed. The parity for any branch can be determined from its parity at Γ in the absence of crossings.

In the honeycomb lattice there are six phonon branches, four in-plane and two out-of-plane. At the Γ point, the in-plane acoustic (A) branches are degenerate and transform as E_1 , while the in-plane optical (O) branches transform as E_2 . For these modes one can define transverse (T) and longitudinal (L) polarizations

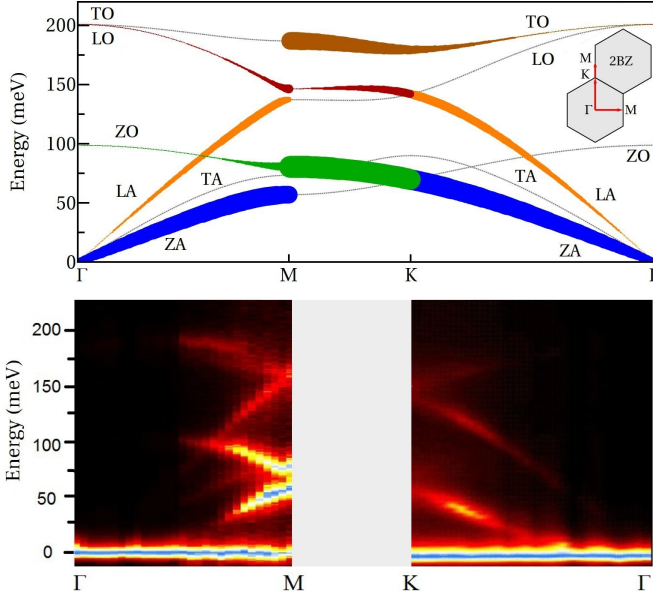


FIG. 2. a) Phonon spectrum for the model in Eqs. 2 and 3 along the high symmetry lines shown in the inset. The area of each dot is proportional to $|M|^2$. Branches with zero intensity within numerical precision are shown as gray dotted lines. Note the selection rules: TA and TO are absent in ΓM and TA, ZO, LO are absent in ΓK . b) Intensity map of the HREELS signal in planar scattering along the same symmetry lines. The agreement for the selection rules of different branches is manifest. Note that the uppermost observed branch at ΓK is the TO mode, which almost overlaps with the LO branch due to the softening induced by a Kohn anomaly which is not captured by our simplified phonon model.

along either ΓK or ΓM , which determines their transformation under reflections. The out-of-plane acoustical (ZA) and optical (ZO) transform as A_1 and B_2 respectively. The parities under both reflections for all six branches are illustrated in Fig. 1 and are summarized as follows: the odd modes are the TA and TO in ΓM , and the TA, LO and ZO in ΓK . The selection rule then states that none of these modes should be observed in an HREELS experiment.

This statement can be checked explicitly with a computation of the HREELS matrix element, Eq. 1. Since our aim is to illustrate selection rules, we will use a minimal force constant model to describe the phonons, following Ref. 18. In this model the in-plane and out-of-plane modes are decoupled and may be treated separately. For the in-plane modes the energy functional includes nearest neighbor bond-stretching α_1 and bond bending γ_1 terms. Denoting the two sites in the unit cell $\alpha = A, B$,

the energy is

$$E = \frac{\alpha_1}{2a^2} \sum_{\vec{x}, n} \left[\vec{\delta}_n \cdot (\vec{u}_{\vec{x}}^A - \vec{u}_{\vec{x}+\vec{\delta}_n}^B) \right]^2 + \frac{\gamma_1}{2a^2} \sum_{\vec{x}, n} \left[(\vec{u}_{\vec{x}+\vec{\delta}_n}^A - \vec{u}_{\vec{x}}^B) \times \vec{\delta}_n - (\vec{u}_{\vec{x}+\vec{\delta}_{n+1}}^A - \vec{u}_{\vec{x}}^B) \times \vec{\delta}_{n+1} \right]^2, \quad (2)$$

where $\vec{x} = n\vec{d}_1 + m\vec{d}_2$ runs through all unit cells and $\vec{\delta}_n$ is the nearest neighbor vector with $n = 1, 2, 3$ and $a = |\vec{\delta}_n|$. The out-of-plane modes are modeled with an out-of-plane bond bending term γ_2

$$E = \frac{\gamma_2}{2} \sum_{\vec{x}, n} \left[u_{z, \vec{x}+\vec{\delta}_n}^A - u_{z, \vec{x}}^B \right]^2. \quad (3)$$

The phonon energies and eigenvectors are obtained from the equations of motion derived from these energies, $m\omega^2 \mathbf{u}^\alpha = \partial E / \partial \mathbf{u}^\alpha$, with m the mass of a carbon atom, and the EELS matrix elements are then computed according to Eq. 1. Note that for out-of-plane phonons of a given q_{\parallel} the value of q_z has to be determined from kinematics from

$$q_z = 2m_e E_I \left[1 - \cos(\theta_I - \theta_S) - \frac{q_{\parallel}^2}{2m_e E_I} \right]^{1/2} \quad (4)$$

where $E_I \sim E_S$ because $\omega_{ph}/E_S < 0.01$ for all phonon energies. The results of this computation are shown in Fig. 2 for the choice of parameters $\alpha_1 = 30 \text{ eV/\AA}^2$, $\gamma_1 = 2.7 \text{ eV/\AA}^2$ and $\gamma_2 = 4.5 \text{ eV/\AA}^2$. The incident energy is $E_I = 26 \text{ eV}$. The different branches are plotted with point size proportional to $|M|^2$ (with absolute scale chosen arbitrarily) and branches with zero intensity are denoted with gray dotted lines. All selection rules are seen to apply as predicted.

IV. COMPARISON WITH EXPERIMENT

To test our predictions for the selection rules, we have measured high resolution EELS spectra of graphene on Ru(0001)^{30–40}. This system is an ideal playground to test symmetries of phonon modes since single domain samples extending up to a millimeter square can be obtained, as revealed by STM studies³³. This is in contrast with other graphene/metal interfaces for which many domains with different azimuthal rotations are found^{41,42}. The experimental phonon dispersion obtained is reported in Fig. 2b. Data was taken for both the ΓK and ΓM directions in scattering conditions enhancing the cross-section for phonon modes in graphitic systems, that is, primary electron beam energy $E_I = 20 \text{ eV}$ and grazing incidence. Other primary energies provide the same phonon dispersion with reduced intensity. Notice that for $E_I = 20 \text{ eV}$, geometrical constraints of the HREELS analyzer do not allow one to reach values of q_{\parallel} sufficient to span the MK line⁴³. For the ΓM and ΓK lines measured in this work,

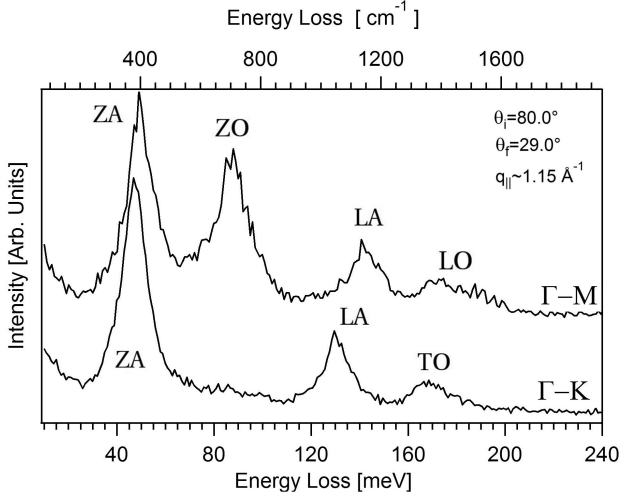


FIG. 3. HREEL spectra for momentum transfer $q_{\parallel} = 1.15 \text{ \AA}^{-1}$ in the ΓM and ΓK directions. Note that the ZO peak is missing in ΓK due to the selection rule, and that the highest energy peak corresponds to different phonons in the two different directions.

the absence of the branches affected by selection rules is manifest, and it is matched by the predictions: TA and TO are absent in ΓM and TA, ZO, LO are absent in ΓK . The general intensity trend is also correct, showing in particular that there is higher intensity for the out of plane branches because $|q_z| > |q_{\parallel}|$.

The selection rule for the ZO in the ΓK direction has not been noticed so far, but here its effects are demonstrated clearly, as the ZO branch completely vanishes in this direction. This effect is illustrated more explicitly in Fig. 3 where the EELS spectra for the ΓK and ΓM directions and $q_{\parallel} = 1.15 \text{ \AA}^{-1}$ are shown as a function of energy. The absence of the ZO peak in ΓK is clearly seen. Fig. 3 also emphasizes that in ΓK , the highest frequency mode that is observed should be labeled TO, contrary to what happens in ΓM , where the highest mode observed is LO.

The phonon dispersion itself also matches reasonably well the experiment, and deviations only occur for the branches affected by Kohn anomalies⁴, a well known limitation of short-ranged models^{44,45} that do not account for the coupling to the π electrons^{46,47}. The modes strongly affected by Kohn anomalies are the TO mode at K , which is shifted down almost to the LO/LA crossing, and the LO at Γ , which should disperse upward faster than the TO, an effect known as overbending. These two effects are missed by our model but can be reproduced with ab-initio calculations including electron-phonon interactions⁴⁷.

V. BREAKING SELECTION RULES

When an experiment reports finite but small intensity coming from forbidden branches, it is important to understand the origin of this effect, as this may provide information on the symmetries of the surface. A first reason why forbidden branches can be observable is simply the finite angle resolution of the detector, which will collect electrons in a momentum range that necessarily goes out of the high symmetry line, introducing some contribution to the intensity. For HREELS experiments this contribution is however negligible. Misalignment of the high symmetry directions will also render selection rules inactive¹⁹. A second mechanism is disorder, which breaks translational symmetry. If momentum is not conserved, electrons collected at a particular angle may have scattered phonons with a distribution of momenta for which the selection rule does not apply. This may also happen for samples with good crystalline order but with domains of random orientation. Thus when selection rules are violated this is commonly interpreted as a signal of the disorder in the sample.

When the previous mechanisms have been excluded, the violation of a selection rule is likely the result of symmetry breaking. For example, the surface under study may be reconstructed with reduced symmetry. Or in our case, the substrate where the graphene monolayer is grown may introduce strain or additional spring constants which again break the symmetry C_{6v} to a lower subgroup. We now explore this last case in more detail, considering two natural examples. First, consider a honeycomb lattice that lies on top of a substrate. This can be modeled by spring constants α_A, α_B connecting each sublattice to the substrate

$$E_{\text{substrate}} = \frac{1}{2} \sum_{\vec{x}} \alpha_A (u_z^A)^2 + \alpha_B (u_z^B)^2. \quad (5)$$

These couplings have typical values of 1-5 eV/ \AA^2 for different metals^{18,48}. For a homogeneous substrate we have $\alpha_A = \alpha_B$, while for a perfectly commensurate triangular lattice substrate, for example for graphene on Ni(111), we have $\alpha_A \neq 0, \alpha_B = 0$. In the latter case, the point group is reduced to C_{3v} and the σ' reflection is broken, so that selection rules in ΓK become inactive for out-of-plane modes. The computed EELS intensity for these two types of substrates is shown in Figs. 4a-b. While both perturbations affect the spectrum, we see that only the second one changes the selection rules, making the ZO visible in ΓK . Since the substrate coupling only affects u_z , selection rules for in-plane modes remain valid.

In the second case, we consider a sample under constant strain u_{ij} , which could be either substrate induced or externally applied. The uniaxial components of strain u_{xx}, u_{yy} break the point group symmetry to C_{2v} (which still has a σ and σ' reflection) while the shear component u_{xy} breaks it to C_2 which has no reflections. Therefore, shear strain will remove selection

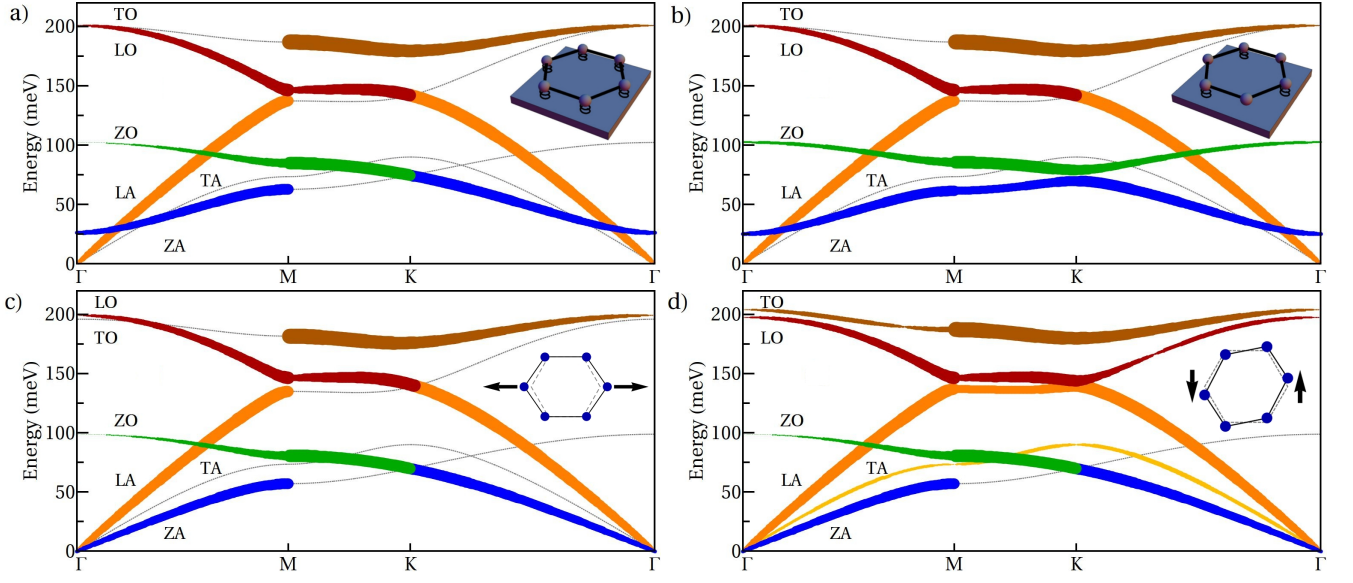


FIG. 4. EELS matrix element for different perturbations. Area of the dots is proportional to $|M|^{1/2}$ for in-plane modes and to $0.2|M|^{1/2}$ for out-of-plane modes so that most and less intense modes (ZA and TA) can be seen in the same plot. a) A homogeneous coupling to the substrate $\alpha_A = \alpha_B = 2\text{eV}/\text{\AA}^2$ lifts the ZA mode but breaks no symmetry, so selection rules are preserved. b) A coupling to only one sublattice $\alpha_A = 4\text{eV}/\text{\AA}^2$ breaks the σ' reflection and renders ΓK selection rules inactive. c) Uniaxial strain $u_{xx} = 0.01$ splits the LO/TO crossing at Γ , but again breaks no reflections. d) Shear strain $u_{xy} = 0.01$ breaks both reflections and renders all selection rules for in-plane modes inactive.

rules completely. Strain can be introduced in our model by modifying the bond stretching couplings. If the relative change in nearest neighbor distance due to strain is $\Delta u_n = (|\vec{\delta}'_n| - |\vec{\delta}_n|)/a \approx \delta_n^i \delta_n^j u_{ij}/a^2$, the change in the bond stretching constant can be parametrized as $\alpha_{1,n} = \alpha_1(1 - \beta \Delta u_n)$, with $\beta = |\partial \log \alpha_1 / \partial \log a|$. In this model β is related to the Gruneisen parameter as $\beta = 4\gamma_{E_{2g}}$, with $\gamma_{E_{2g}} \approx 2$ as estimated from the Raman splitting of the G mode under strain⁴⁹. The bond stretching energy in the presence of strain is modified to

$$E_{\text{strain}} = \frac{1}{2a^2} \sum_{\vec{x},n} \alpha_{1,n} \left[\vec{\delta}_n \cdot (\vec{u}_x^A - \vec{u}_{x+\delta_n}^B) \right]^2. \quad (6)$$

The EELS matrix element for these two types of strains is shown in Figs. 4c-d. Again, both perturbations change the spectrum, but only the second one changes the intensity pattern: since shear strain breaks both reflections, all in-plane modes become visible.

VI. DISCUSSION

One of the conclusions of this work is that the selection rules usually quoted in the literature have been often incomplete or misunderstood. The confusion may originate from the fact that in the EELS literature, surface phonons are classified into two groups: sagittal plane (SP) phonons have polarization parallel to the sagittal (or scattering) plane, while shear horizontal (SH) phonons

have polarization perpendicular to this plane¹. This classification has sometimes lead to a formulation of selection rules that states that SH modes are not observed in planar scattering. This formulation can be misleading because it implicitly assumes that the polarization behaves as a vector under reflections. When this is the case, SH modes are indeed odd under reflection, while SP modes are even. For example, this happens for the in-plane acoustic modes which transform as an E_1 representation. One may thus identify the LA as SP and the TA as SH, which is not observed. However, this formulation is incorrect for an arbitrary representation, for example for the optical in-plane phonons (LO, TO), which transform as E_2 . In the ΓK direction, the TO has polarization perpendicular to the scattering plane and is thus labeled as SHO^{15,17}, SH^{*16,20,25,50} or simply SH^{18,22}. Nevertheless it is even under reflection and has no selection rule, contrary to common belief¹⁶. In the same way, the LO is SP (parallel to the plane) but is odd under reflection and should be absent. When only one of the LO/TO phonons is observed, the label that should be assigned to it is thus TO (or SH).

A similar situation occurs for the ZO (a B_2 representation) in the ΓK direction, which is polarized in the z direction (also SP) but is odd under reflection. This selection rule has been missed until now because this mode is not a shear mode, but as Fig. 3 clearly shows, this mode is not observed on graphene on Ru(0001) in ΓK , but is visibly observed in ΓM . This is also consistent with intensity data available in the literature. The ZO

in ΓK is almost invisible in graphene on Ni(111) when intercalated with Ag²⁵, but is clearly visible along ΓM on graphene on BC₃²³.

Our analysis of selection rules also sheds light on previous EELS experiments performed on graphite. The surface phonons of graphite in the (001) direction are very similar to those of graphene because of the weak inter-layer coupling. However, the planar symmetry group is actually C_{3v} because the graphene layers are stacked in an alternating AB sequence: only one sublattice has carbon atoms below. As a result, the σ' reflection is broken and there are no selection rules in the ΓK direction. The only remaining selection rules apply to the TA and TO phonons in the ΓM direction. The same analysis would apply to any related material with C_{3v} symmetry such as BN⁵¹ or silicene^{52,53}.

The EELS spectra of graphite in Ref. 54 were recorded in a sample containing domains with random azimuthal direction. For this reason, the TA mode was clearly observed. However, in Ref. 17 both TO and TA were observed in the ΓM direction, which is inconsistent with the selection rule. As noted in Ref. 46, in this experiment TA and ZO cross before reaching the M point, which is also inconsistent with both theory calculations and with more recent X-ray data⁵⁵ where there is a clear TA/ZO crossing at M . Since the crossing in Ref. 17 occurs approximately at the same q as the crossing in the ΓK and the selection rule is being violated, it appears possible that the measurement may have contained several orientational domains as well. It would be interesting to see new experimental data to shed light on this issue.

In summary, in this work we have provided the selection rules for the measurement of the phonon spectrum of the honeycomb lattice in planar scattering, showing that some selection rules have been overlooked. These are however manifest in our HREELS spectra in graphene on Ru(0001). We hope that our work will serve as a guideline for further experiments measuring phonon dispersions in graphene or other materials.

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VII. APPENDIX

A. Experimental methods

Experiments were carried out in an ultra-high vacuum (UHV) chamber operating at a base pressure of $5 \cdot 10^{-11}$ mbar. The sample was a single crystal of Ru(0001) which

was cleaned by repeated cycles of ion sputtering and annealing at 1300 K. Surface cleanliness and order were checked using Auger electron spectroscopy (AES) and low-energy electron diffraction (LEED) measurements, respectively.

Graphene was obtained by dosing ethylene onto the clean Ru(0001) substrate held at 1150 K. The MLG was reached upon an exposure of $3 \cdot 10^{-8}$ mbar for ten minutes (24 L. 1 L = $1.33 \cdot 10^{-6}$ mbars). After removing the C₂H₄ gas from the chamber the temperature was held at 1150 K for further 60 seconds. The attained LEED pattern (shown in Fig. 5) is essentially similar to those previously reported^{30,33}. Around each spot of the (1x1), additional spots due to the (12x12) reconstruction of the overlayer were revealed. Only MLG has been observed in the whole sample, as in STM and He atom scattering experiments by Politano et al. reported elsewhere^{34,37}.

HREELS experiments were performed by using an electron energy loss spectrometer (Delta 0.5, SPECS). The energy resolution of the spectrometer was degraded to 4 meV so as to increase the signal-to-noise ratio of loss peaks. Dispersion of the loss peaks, i.e., $E_{loss}(q_{||})$, was measured by moving the analyzer while keeping the sample and the monochromator in a fixed position. To measure the dispersion relation, values for the parameters E_I , impinging energy and θ_I , the incident angle, were chosen so as to obtain the highest signal-to-noise ratio. The primary beam energy used for the dispersion, $E_I = 20$ eV, provided, in fact, the best compromise among surface sensitivity, the highest cross-section for mode excitation and $q_{||}$ resolution. As

$$q_{||} = \hbar (k_I \sin \theta_I - k_S \sin \theta_S),$$

the parallel momentum transfer $q_{||}$ depends on E_I , E_{loss} , θ_I and θ_S according to

$$q_{||} = \frac{\sqrt{2mE_I}}{\hbar} \left(\sin \theta_I - \sqrt{1 - \frac{E_{loss}}{E_I}} \sin \theta_S \right)$$

where E_{loss} is the energy loss and θ_S is the electron scattering angle⁵⁶. Accordingly, the integration window in reciprocal space is⁵⁷

$$\Delta q_{||} \approx \frac{\sqrt{2mE_I}}{\hbar} \left(\cos \theta_I + \sqrt{1 - \frac{E_{loss}}{E_I}} \cos \theta_S \right) \cdot \alpha$$

where α is the angular acceptance of the apparatus⁵⁸ ($\pm 0.5^\circ$ in our case). For the investigated range of $q_{||}$, the indeterminacy has been found to range from 0.005 (near Γ) to 0.022 \AA^{-1} (for higher momenta). To obtain the intensities of phonon modes, a polynomial background was subtracted from each spectrum. All measurements were made at room temperature.

B. Appendix B: Strain and Gruneisen parameter

The effect of strain was described in the main text as a change in the bond stretching constant, which becomes

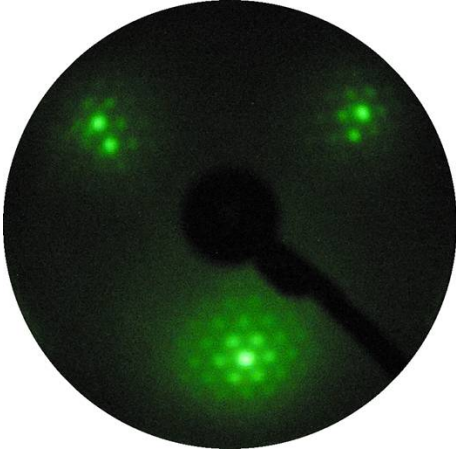


FIG. 5. LEED pattern of graphene on Ru(0001), recorded at $E_p = 74$ eV and room temperature.

neighbor dependent $\alpha_{1,n} = \alpha_1(1 - \beta\delta_n^i\delta_n^j u_{ij}/a^2)$. The parameter β is related to the Gruneisen parameter for

the optical phonon at Γ , defined as^{49,59}

$$\gamma_{E_{2g}} = \frac{1}{\omega_{E_{2g}}} \frac{\partial \omega_{E_{2g}}}{\partial u_h}, \quad (7)$$

where $u_h = u_{xx} + u_{yy}$. To show this relation, consider the total energy in the presence of strain

$$E = \frac{1}{2a^2} \sum_{\vec{x},n} \alpha_1 (1 - \beta\delta_n^i\delta_n^j u_{ij}/a^2) \left[\vec{\delta}_n \cdot (\vec{u}_x^A - \vec{u}_{x+\delta_n}^B) \right]^2 + \frac{\gamma_1}{2a^2} \sum_{\vec{x},n} \left[(\vec{u}_{x+\delta_n}^A - \vec{u}_x^B) \times \vec{\delta}_n - (\vec{u}_{x+\delta_{n+1}}^A - \vec{u}_x^B) \times \vec{\delta}_{n+1} \right]^2, \quad (8)$$

where we assume that γ_1 does not change. The equation of motion is

$$M(\omega^2 - \omega_{E_{2g}}^2)u_i = -3\alpha_1 \frac{\beta}{4} (u_h \mathcal{I}_{ij} + 2u_{ij})u_j, \quad (9)$$

with $\omega_{E_{2g}}^2 = (3\alpha_1 + 9\gamma_1)/M$ the frequency of the optical mode, and we have set $\vec{u}^A = -\vec{u}^B = \vec{u}$ for the optical mode. Neglecting γ_1 compared with α_1 , specifying to uniaxial strain $u_{xy} = 0$ and taking the square root for small strain we obtain

$$\omega_{\pm} \approx \omega_{E_{2g}} - \omega_{E_{2g}} \frac{\beta}{8} (2u_h \pm (u_{xx} - u_{yy})), \quad (10)$$

which gives $\gamma_{E_{2g}} = \beta/4$.

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